

20 V, single P-channel Trench MOSFET 20 July 2012

Product data sheet

1. Product profile

1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- 3 kV ESD protected
- Trench MOSFET technology
- Low threshold voltage

1.3 Applications

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- Relay driver
- High-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-3.7	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -3.2 A; T _j = 25 °C		-	50	66	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 ☐ 2 TO-236AB (SOT23)	G G S 017aaa259

3. Ordering information

Table 3. Ordering information					
Type number Package					
	Name	Description	Version		
PMV50UPE	TO-236AB	plastic surface-mounted package; 3 leads	SOT23		

4. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMV50UPE	%CZ

[1] % = placeholder for manufacturing site code

5. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-3.7	А
		V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-3.2	А
		V_{GS} = -4.5 V; T_{amb} = 100 °C	[1]	-	-2	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-12.8	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	500	mW

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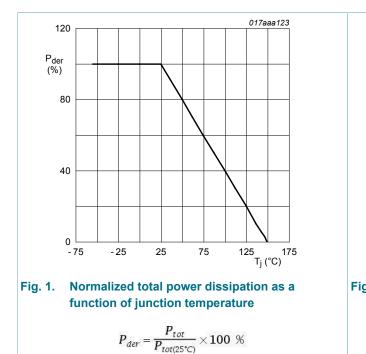
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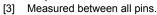
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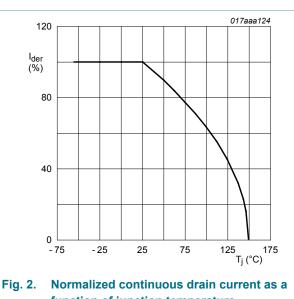
Symbol	Parameter	Conditions		Min	Max	Unit
			[1]	-	955	mW
		T _{sp} = 25 °C		-	3570	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	-1	А
ESD maximu	m rating					_
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	3000	V

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

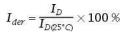
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





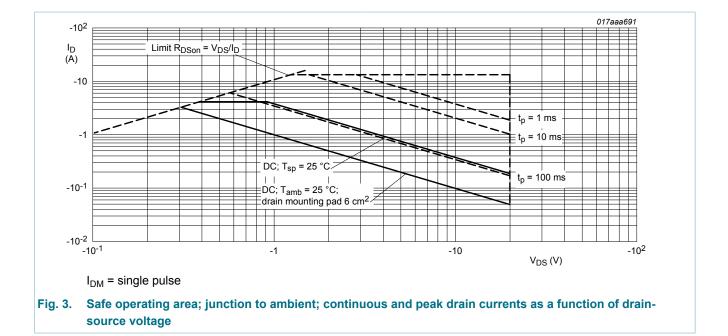


function of junction temperature



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6. Thermal characteristics

Table 6. The	ermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	[1]	-	218	250	K/W
		[2]	-	114	130	K/W	
	ampient		[3]	-	80	92	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	30	35	K/W

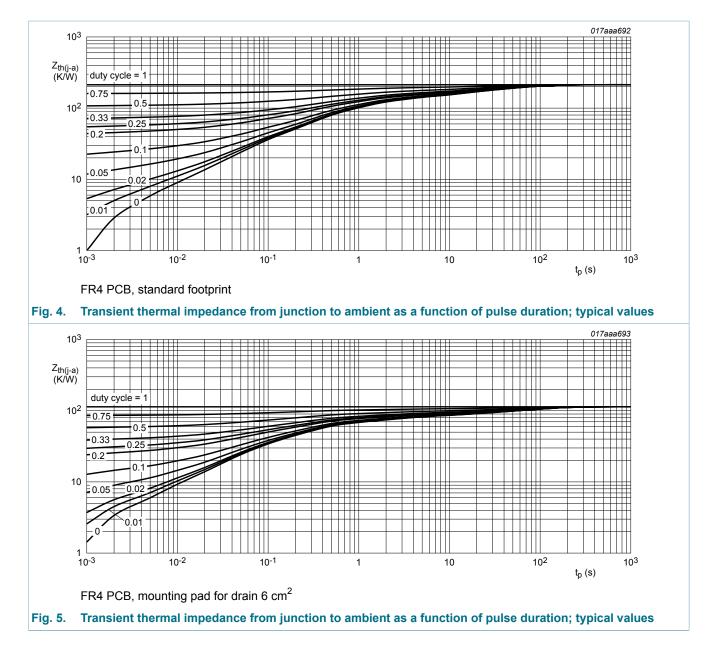
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm², t \leq 5 s.

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7. Characteristics

Table 7. Cl	haracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C		-20	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = -250 μA; V _{DS} = V _{GS} ; T _j = 25 °C		-0.47	-0.6	-0.9	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C		-	-	-1	μA
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 150 °C		-	-	-10	μA
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I _{GSS}	gate leakage current	V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I _D = -3.2 A; T _j = 25 °C	-	50	66	mΩ
	resistance	V _{GS} = -4.5 V; I _D = -3.2 A; T _j = 150 °C	-	73	96	mΩ
		V_{GS} = -2.5 V; I_D = -2.1 A; T_j = 25 °C	-	57	81	mΩ
		V _{GS} = -1.8 V; I _D = -2.1 A; T _j = 25 °C	-	70	110	mΩ
9fs	forward transconductance	V _{DS} = -5 V; I _D = -3.2 A; T _j = 25 °C	-	18	-	S
Dynamic cl	haracteristics	· · · ·		1	1	
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -3.2 A; V _{GS} = -4.5 V;	-	10.5	15.7	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.2	-	nC
Q _{GD}	gate-drain charge		-	2.7	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	24	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	106	-	pF
C _{rss}	reverse transfer capacitance		-	14.6	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -3.2 A; V _{GS} = -4.5 V;	-	400	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	700	-	ns
t _{d(off)}	turn-off delay time		-	2180	-	ns
t _f	fall time		-	8800	-	ns

Source-drain diode

source-drain voltage

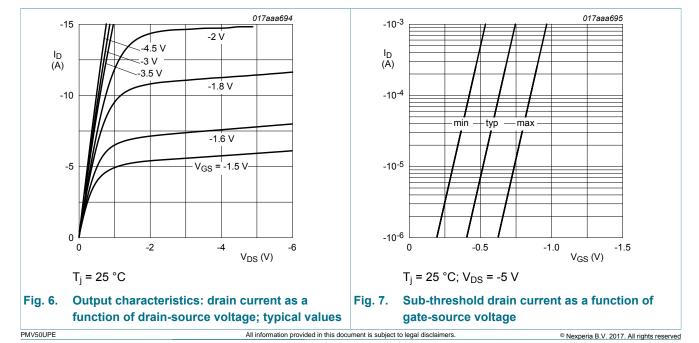
 V_{SD}

I_S = -1 A; V_{GS} = 0 V; T_j = 25 °C

-1.2 V

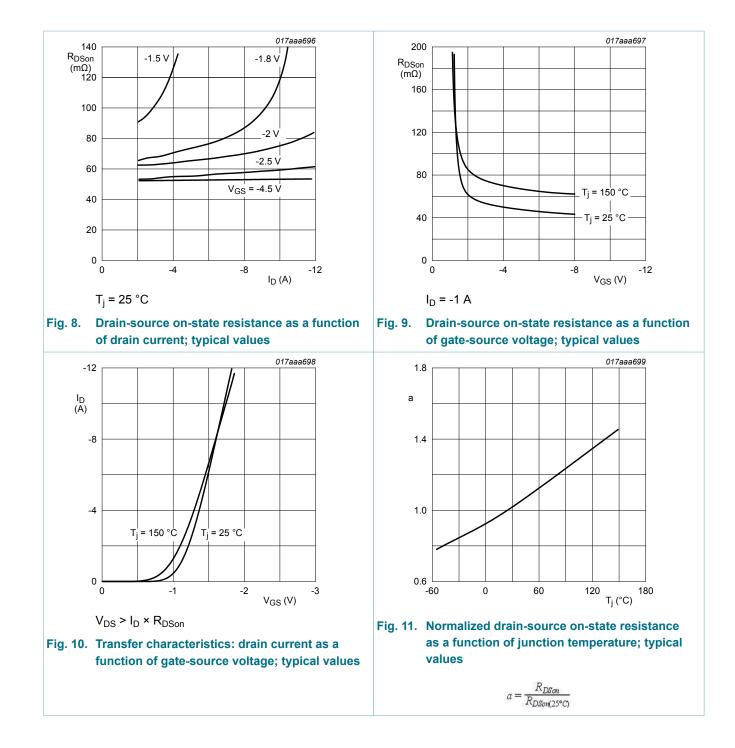
-0.8

-



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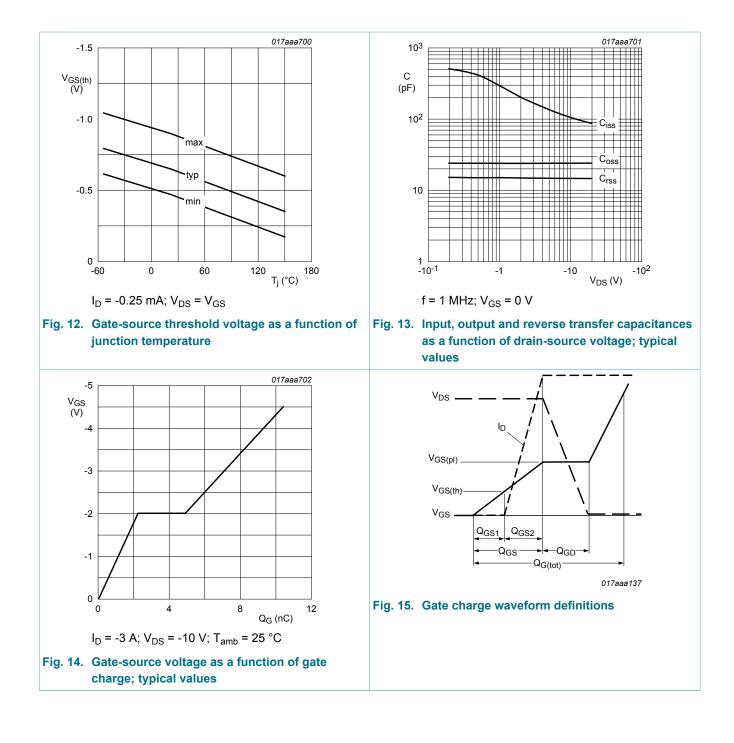
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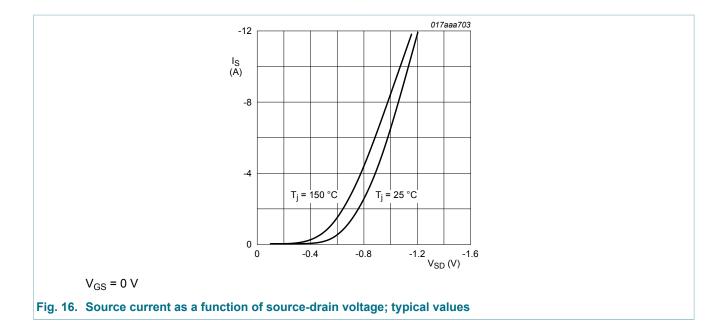
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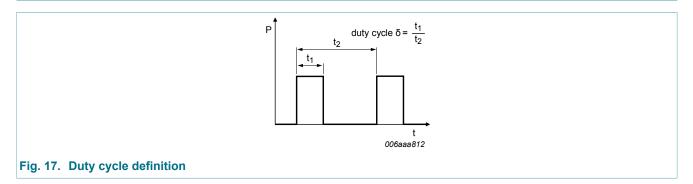


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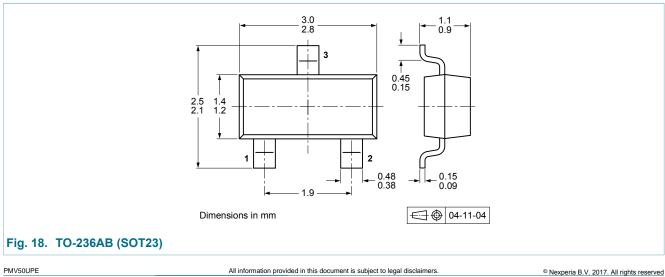
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Test information 8.

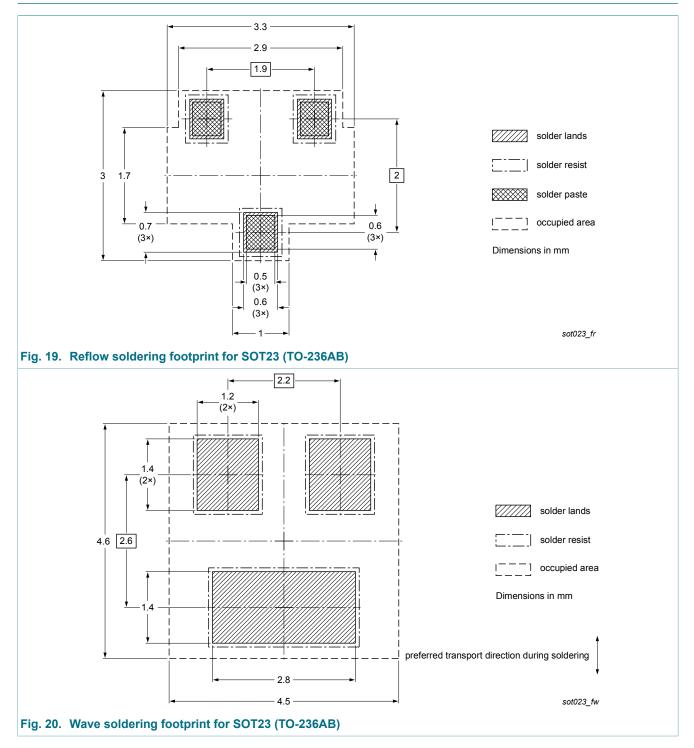


Package outline 9.



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10. Soldering



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11. Revision history

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PMV50UPE v.1	20120720	Product data sheet	-	-	

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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